

## Synthesis and Structural Characterization of SnO<sub>2</sub> Electron Transport Layer in Perovskite Solar Cells

Hongzhou Dong<sup>1</sup>, Chenglin Gao<sup>1</sup>, Xichang Bao<sup>2</sup>, Liyan Yu<sup>1</sup>, Lifeng Dong<sup>1,3</sup>

<sup>1</sup>. College of Materials Science and Engineering, Qingdao University of Science and Technology, Qingdao 266042, China

<sup>2</sup>. CAS Key Laboratory of Bio-based Materials, Qingdao Institute of Bioenergy and Bioprocess Technology, Chinese Academy of Sciences, Qingdao 266101, China

<sup>3</sup>. Department of Physics, Hamline University, St. Paul, MN 55104, USA

Energy crisis and environmental pollution become the problems that more and more researchers focus on, and perovskite solar cells have attracted most interesting due to their high-power conversion efficiency (PCE) of over 20% [1]. TiO<sub>2</sub> is usually utilized as electron transporting layer for perovskite solar cells, but its high synthesis temperature of 450 °C has limited its applications in flexible electronics. In comparison to TiO<sub>2</sub>, SnO<sub>2</sub> can be synthesized through low temperature solution process and exhibit similar or even better electrical and optical properties. In this study, we synthesize SnO<sub>2</sub> by spin-coating followed by thermal treatment at 200 °C and study its structural and photoelectrical properties.

Figures 1a-b demonstrate schematic structure and energy band diagram of a perovskite solar cell, respectively. For the fabrication of a solar cell, fluorine doped tin oxide (FTO) glass substrate was firstly cleaned and treated with O<sub>2</sub> plasma to improve wettability. SnO<sub>2</sub> was then synthesized on the surface of the FTO substrate by spin-coating SnCl<sub>4</sub>·5H<sub>2</sub>O precursor at 4000 rpm for 20 s, followed by thermal treatment at 200 °C for 30 min. Then, perovskite CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> and thiophene copolymer **P1** as hole transporting layer [2] were formed on top of SnO<sub>2</sub> layer by spin-coating successively. At the end, the sample was taken into a thermal evaporation chamber, where Ag electrode was deposited. Surface morphology of the films was characterized by scanning electron microscopy (SEM, Hitachi S-4800). Current-voltage (*J-V*) curves of solar cells were tested under 100 mW/cm<sup>2</sup> illumination of AM 1.5G with a Newport solar simulator through a Keithley 2420 source measurement unit [3].

As shown in Figure 2a, a compact SnO<sub>2</sub> nanocrystalline film is formed on the FTO substrate with a thickness of circa 30 nm (Figure 2c). Figure 2b shows high quality perovskite CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> film with relatively large grains and excellent surface coverage is coated on the top of the SnO<sub>2</sub> layer. As given in Figure 2d, short-circuit current density (*J*<sub>SC</sub>), open-circuit voltage (*V*<sub>OC</sub>), fill factor (FF) and PCE of the perovskite solar cells are 9.22 mA/cm<sup>2</sup>, 1.05 V, 65.01%, and 6.27%, respectively. This indicates that SnO<sub>2</sub> film can be successfully synthesized by low temperature solution process to replace TiO<sub>2</sub> or organic PEDOT/PSS as electron transporting layer for perovskite solar cells, and the PCE can be improved by optimizing parameters of solution process [4].

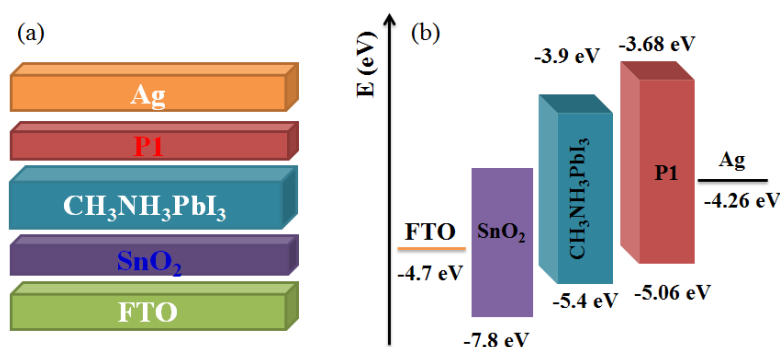
### References:

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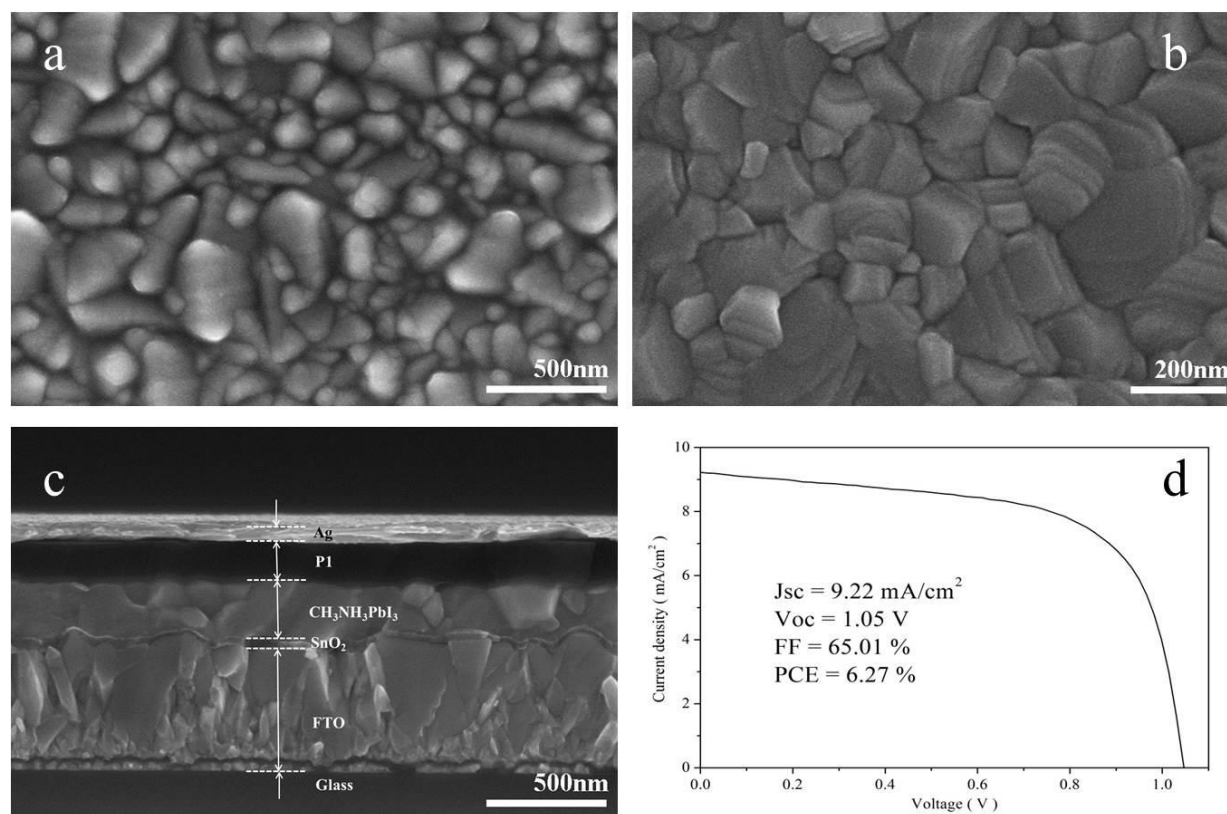
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[4] This research was supported by the National Natural Science Foundation of China (21776147 & 21606140), the International Science & Technology Cooperation Program of China (2014DFA60150), the Department of Science and Technology of Shandong Province (2016GGX104010), and Shandong Province Higher Educational Science and Technology Program (J16LA14).



**Figure 1.** Schematic structure of a perovskite solar cell (a) and corresponding energy band diagram (b).



**Figure 2.** Top-view SEM images of  $\text{SnO}_2$  film coated on FTO substrate (a) and perovskite  $\text{CH}_3\text{NH}_3\text{PbI}_3$  film coated on the  $\text{SnO}_2$  film (b). Cross sectional SEM image (c) and J-V curve (d) of the perovskite solar cell.